# NSN 5962-01-283-8233

Memory Microcircuit - Page 1 of 1



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# Body Length:

Between 1.235 inches and 1.290 inches

# Body Width:

Between 0.510 inches and 0.600 inches

# **Body Height:**

Between 0.140 inches and 0.180 inches

# **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### Features Provided:

Electrostatic sensitive and hermetically sealed and burn in and programmable and 3-state output and bipolar

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

14 input

#### **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

7.0 volts power source

# Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

# Memory Device Type:

Rom

# Memory Capacity:

Unknown

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

24 printed circuit

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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